TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1150

Low Frequency Amplifier Applications

Unit: mm

High hFE: hFE = 100~320
Complementary to 2SC2710.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-35	V
Collector-emitter voltage	V _{CEO}	-30	٧
Emitter-base voltage	V _{EBO}	-5	٧
Collector current	IC	-800	mA
Base current	ΙB	-160	mA
Collector power dissipation	PC	300	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the

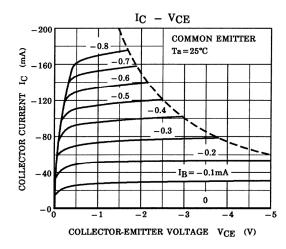
Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

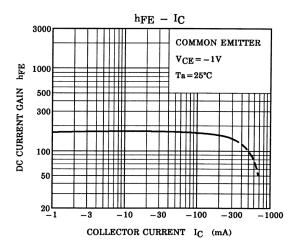
Weight: 0.13 g (typ.)

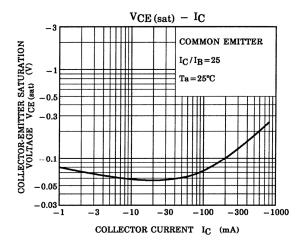
Electrical Characteristics (Ta = 25°C)

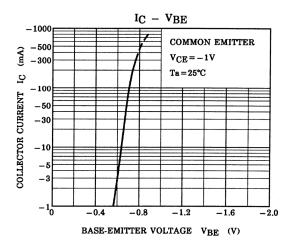
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -30 \text{ V}, I_E = 0$	_	_	-0.1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-0.1	μА
Collector-emitter breakdown voltage	V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-30	_	_	V
DC current gain	h _{FE (1)} (Note)	V _{CE} = -1 V, I _C = -100 mA	100	_	320	
	h _{FE (2)}	$V_{CE} = -1 \text{ V, } I_{C} = -700 \text{ mA}$	35	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = -500 \text{ mA}, I_B = -20 \text{ mA}$	_	_	-0.7	V
Base-emitter voltage	V _{BE}	$V_{CE} = -1 \text{ V, } I_{C} = -10 \text{ mA}$	-0.5	_	-0.8	V
Transition frequency	f _T	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	_	120	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	-	19	_	pF

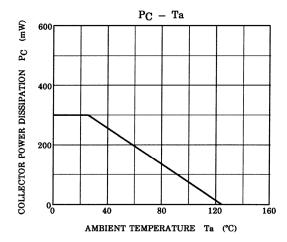
Note: hFE (1) classification O: 100~200, Y: 160~320











2 2007-11-01

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
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3 2007-11-01